

Dual EIA-423/EIA-232D Line Driver

The MC3488A dual is single–ended line driver has been designed to satisfy the requirements of EIA standards EIA–423 and EIA–232D, as well as CCITT X.26, X.28 and Federal Standard FIDS1030. It is suitable for use where signal wave shaping is desired and the output load resistance is greater than 450 ohms. Output slew rates are adjustable from 1.0 μs to 100 μs by a single external resistor. Output level and slew rate are insensitive to power supply variations. Input undershoot diodes limit transients below ground and output current limiting is provided in both output states.

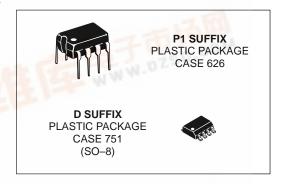
The MC3488A has a standard 1.5 V input logic threshold for TTL or NMOS compatibility.

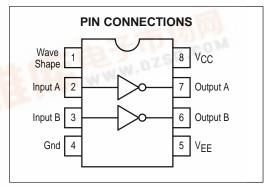
- PNP Buffered Inputs to Minimize Input Loading
- Short Circuit Protection
- Adjustable Slew Rate Limiting
- MC3488A Equivalent to 9636A
- Output Levels and Slew Rates are Insensitive to Power Supply Voltages
- No External Blocking Diode Required for VFF Supply
- Second Source μA9636A

MC3488A

DUAL EIA-423/EIA-232D DRIVER

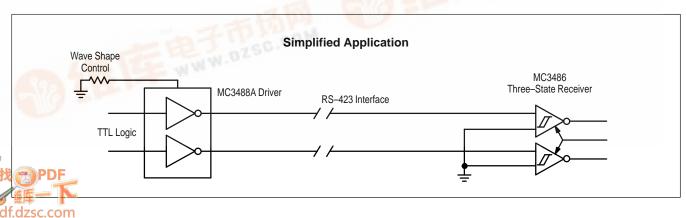
SEMICONDUCTOR TECHNICAL DATA





ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC3488AP1	$T_A = 0 \text{ to } +70^{\circ}\text{C}$	Plastic DIP
MC3488AD	1A = 0 to +70 C	SO-8



MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Power Supply Voltages	V _{CC}	+ 15 – 15	V
Output Current Source Sink	l _O +	+ 150 - 150	mA
Operating Ambient Temperature	TA	0 to + 70	°C
Junction Temperature Range	TJ	150	°C
Storage Temperature Range	T _{stg}	- 65 to + 150	°C

RECOMMENDED OPERATING CONDITIONS

Characteristic	Symbol	Min	Тур	Max	Unit
Power Supply Voltages	V _{CC} V _{EE}	10.8 - 13.2	12 – 12	13.2 - 10.8	V
Operating Temperature Range	TA	0	25	70	°C
Wave Shaping Resistor	RWS	10	-	1000	kΩ

TARGET ELECTRICAL CHARACTERISTICS (Unless otherwise noted, specifications apply over recommended operating conditions)

Characteristic	Symbol	Min	Тур	Max	Unit
Input Voltage – Low Logic State	V _{IL}	-	-	0.8	V
Input Voltage – High Logic State	V _{IH}	2.0	-	-	V
Input Current – Low Logic State (V _{IL} = 0.4 V)	IIL	- 80	-	_	μА
Input Current – High Logic State (V _{IH} = 2.4 V) (V _{IH} = 5.5 V)	l _{IH1}	- -	- -	10 100	μА
Input Clamp Diode Voltage (I _{IK} = -15 mA)	VIK	– 1.5	-	_	V
Output Voltage – Low Logic State $ \begin{array}{ll} (R_L = \infty) & EIA423 \\ (R_L = 3.0 \ k\Omega) & EIA232D \\ (R_L = 450 \ \Omega) & EIA423 \end{array} $	VOL	- 6.0 - 6.0 - 6.0	- - -	- 5.0 - 5.0 - 4.0	V
Output Voltage – High Logic State $ \begin{array}{ll} (R_L = \infty) & EIA423 \\ (R_L = 3.0 \ k\Omega) & EIA232D \\ (R_L = 450 \ \Omega) & EIA423 \end{array} $	VOH	5.0 5.0 4.0	- - -	6.0 6.0 6.0	V
Output Resistance (R _L \geq 450 Ω)	RO	-	25	50	Ω
Output Short–Circuit Current (Note 2) (V _{in} = V _{out} = 0 V) (V _{in} = V _{IH} (Min), V _{out} = 0 V)	losh lost	– 150 + 15	- -	- 15 + 150	mA
Output Leakage Current (Note 3) $(V_{CC} = V_{EE} = 0 \text{ V}, -6.0 \text{ V} \leq V_0 \leq 6.0 \text{ V})$	lox	- 100	-	100	μΑ
Power Supply Currents (R _W = 100 k Ω , R _L = ∞ , V _{IL} \le V _{in} \le V _{IH})	ICC IEE	_ _ 18	_ _	+ 18 -	mA

NOTES: 1. Devices should not be operated at these values. The "Electrical Characteristics" provide conditions for actual device operation.
2. One output shorted at a time.
3. No V_{EE} diode required.

TRANSITION TIMES (Unless otherwise noted, C_L = 30 pF, f = 1.0 kHz, V_{CC} = - V_{EE} = 12.0 V \pm 10%, T_A = 25°C, R_L = 450 Ω . Transition times measured 10% to 90% and 90% to 10%)

Characteristic	Symbol	Min	Тур	Max	Unit
Transition Time, Low–to–High State Output $(R_W = 10 \text{ k}\Omega)$	tтLН	0.8	_	1.4	μs
$(R_W = 100 \text{ k}\Omega)$ $(R_W = 500 \text{ k}\Omega)$		8.0 40		14 70	
(R _W = 1000 kΩ)		80	_	140	_
Transition Time, High–to–Low State Output ($R_W = 10 \text{ k}\Omega$)	tthl	0.8	_	1.4	μs
$(R_W = 100 \text{ k}\Omega)$ $(R_W = 500 \text{ k}\Omega)$		8.0 40	_ _	14 70	
$(R_{W} = 1000 \text{ k}\Omega)$		80	_	140	

Figure 1. Test Circuit and Waveforms for Transition Times

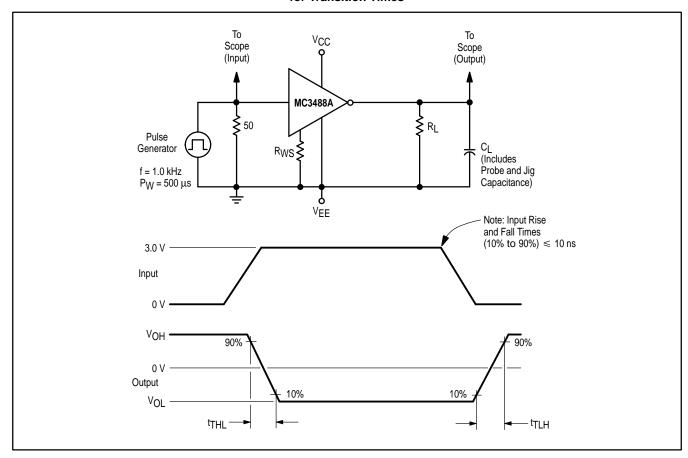


Figure 2. Output Transition Times versus Wave Shape Resistor Value

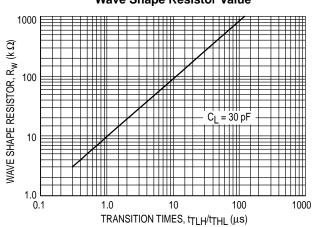


Figure 3. Input/Output Characteristics versus Temperature

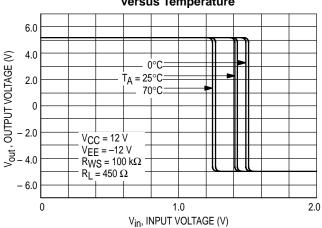
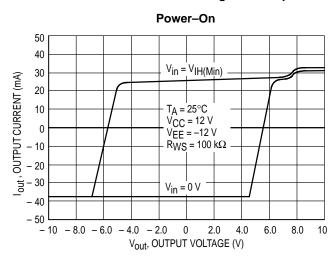


Figure 4. Output Current versus Output Voltage



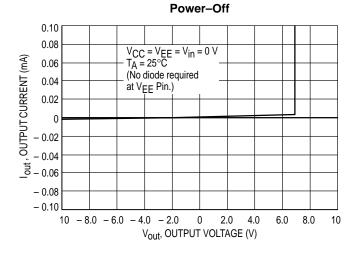


Figure 5. Supply Current versus Temperature

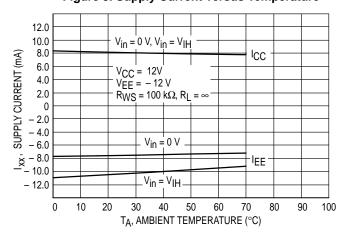
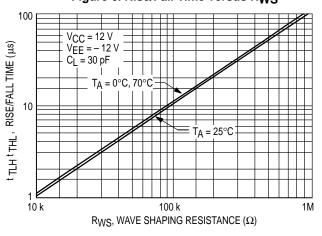
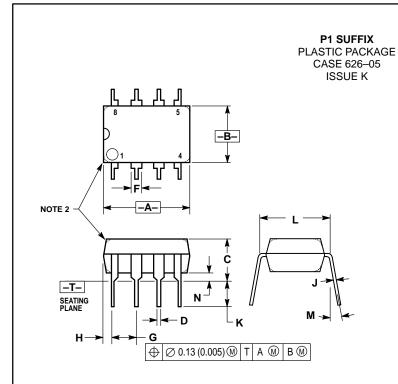


Figure 6. Rise/Fall Time versus RWS



OUTLINE DIMENSIONS



NOTES:

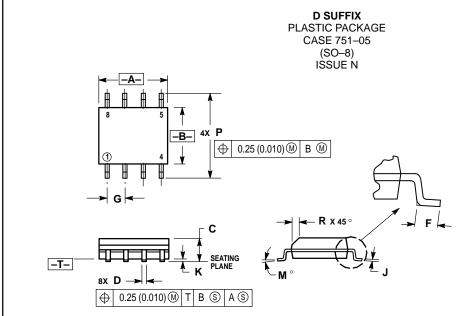
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 1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.

 2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).

 3. DIMENSIONING AND TOLERANCING PER ANSIVALEM AND TOLERANCING PER ANSIVALEM AND TOLERANCING PER ANSI
- Y14.5M, 1982.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	9.40	10.16	0.370	0.400	
В	6.10	6.60	0.240	0.260	
С	3.94	4.45	0.155	0.175	
D	0.38	0.51	0.015	0.020	
F	1.02	1.78	0.040	0.070	
O	2.54	BSC	0.100	BSC	
Н	0.76	1.27	0.030	0.050	
J	0.20	0.30	0.008	0.012	
K	2.92	3.43	0.115	0.135	
Т	7.62 BSC		0.300 BSC		
М		10°		10°	
N	0.76	1.01	0.030	0.040	



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) DED SIDE
- 4. MAAIMUM MOLLE PROTRUSION 0.13 (0.000)
 PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL
 IN EXCESS OF THE D DIMENSION AT
 MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.196	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.18	0.25	0.007	0.009	
K	0.10	0.25	0.004	0.009	
M	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

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